Ultra-Low 0.5Ω Dual SPDT Analog Switch
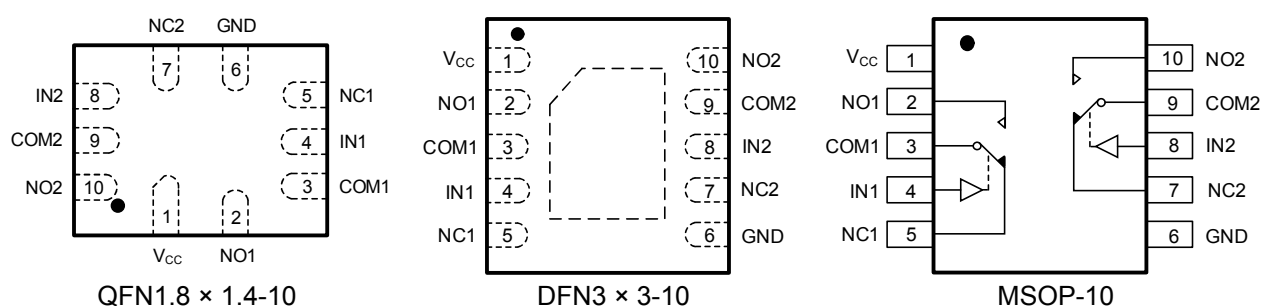
DESCRIPTION

The SUM5223 is an advanced CMOS analog switch fabricated in Sub−micron silicon gate CMOS technology. The part also features guaranteed Break Before Make (BBM) switching, assuring the switches never short the driver.

FEATURES

- Ultra-Low R_{ON} < 0.55 Ω at V_{CC} = 4.3 V
- Single Supply Operation from 1.65 V ~ 5.5 V
- Low Crosstalk
- Full 0 ~ V_{CC} Signal Handling Capability
- High Off − Channel Isolation
- Low Standby Current, < 50 nA
- Low Distortion
- R_{ON} Flatness of 0.15 Ω
- High Continuous Current Capability: ±300 mA Through Each Switch
- Applications in Cell Phone Audio Block/Speaker and Earphone Switching Ring−Tone Chip/Amplifier Switching/Modems
- ESD : Human Body Model > 4000 V (Reference Document: MIL-STD-883H Method 3015.8)
- Package: QFN1.8 × 1.4-10; DFN3 × 3-10; MSOP-10

PIN CONFIGURATION (Top View)

QFN1.8 × 1.4-10

DFN3 × 3-10

MSOP-10

ORDER INFORMATION

Model	Package	Ordering Number	Packing Option
SUM5223	QFN1.8 × 1.4-10	SUM5223QN	Tape and Reel, 3000
	DFN3 × 3-10	SUM5223DNB10	Tape and Reel, 3000
	MSOP-10	SUM5223MS	Tape and Reel, 4000

PIN DESCRIPTIONS

Pin	Symbol	Description
1	V_{CC}	Power Supply
2	NO1	Independent Channels
3	COM1	Common Channels
4	IN1	Controls
5	NC1	Independent Channels
6	GND	Ground
7	NC2	Independent Channels
8	IN2	Controls
9	COM2	Common Channels
10	NO2	Independent Channels

TRUTH TABLE

IN1, IN2	NO1, NO2	NC1, NC2
0	OFF	ON
1	ON	OFF

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Supply Voltage	V_{CC}	-0.5 to 6.0	V
Analog Input Voltage	V_{IS}	-0.5 to V_{CC} + 0.5	V
Digital Select Input Voltage	V_{IN}	-0.5 to 6.0	V
Output Voltage	V_{OUT}	-0.5 to V_{CC} + 0.5	V
Continuous DC Current from COM to NC/NO	Ian1	±300	mA
Peak Current from COM to NC/NO, 10 duty cycle (Note 1)	Ian1-pk1	±500	mA
Continuous DC Current into COM/NO/NC with respect to V_{CC} or GND	Iclmp	±100	mA

Stresses beyond those listed under "ABSOLUTE MAXIMUM RATINGS" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 1. Defined as 10% ON, 90% off duty cycle.

CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SUMSEMI recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SUMSEMI reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SUMSEMI sales office to get the latest datasheet.

RECOMMENDED OPERATING CONDITIONS

Characteristic		Symbol	Min	Max	Unit
DC Supply Voltag		V_{CC}	1.65	5.5	V
Digital Select Input Voltage		V_{IN}	GND	5.5	V
Analog Input Voltage		V_{IS}	GND	V_{CC}	V
Operating Temperature Range		T_A	-45	+85	℃
Input Rise or Fall Time, SELECT	V_{CC} = 1.6 V to 2.7 V	t_R, t_F	0	20	ns/V
	V_{CC} = 3.0 V to 5.5 V		0	10	

ELECTRICAL CHARACTERISTICS (DC)

Symbol	Parameter	Test Conditions	V_{CC} ± 10%	T_A = 25℃			T_A = -40℃ to +85℃		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	High-Level Input Voltage, Select Inputs		1.65 ~ 1.95	1.1			1.1		V
			2.3 ~ 2.5	1.2			1.2		
			2.7 ~ 3.0	1.3			1.3		
			3.0 ~ 3.6	1.4			1.4		
			4.3	1.5			1.5		
V_{IL}	Low−Level Input Voltage, Select Inputs		1.65 ~ 1.95			0.25		0.25	V
			2.3 ~ 2.5			0.25		0.25	
			2.7 ~ 3.0			0.25		0.25	
			3.0 ~ 3.6			0.30		0.30	
			4.3			0.40		0.40	
I_{IN}	Maximum Input Leakage Current, Select Inputs	V_{IN} =V_{CC} or GND	4.3			±0.1		±1.0	µA
I_{OFF}	Power Off Leakage Current	V_{IN} =V_{CC} or GND	0			±0.5		±2.0	µA
I_{CC}	Maximum Quiescent Supply Current (Note 2)	Select, V_{IS} = V_{CC} or GND	1.65 ~ 4.3			±1.0		±2.0	µA
$I_{NO\ (OFF)}$ $I_{NC\ (OFF)}$	NC or NO Off Leakage Current	V_{IN} = V_{IL} or V_{IH} V_{NO} or V_{NC} = 0.3 V V_{COM} = 4.0 V	4.3	-5.0		5.0	-10	10	nA
$I_{COM\ (ON)}$	COM ON Leakage Current (Note 3) V_{IN} = V_{IL} or V_{IH}, V_{NO} = 0.3 V or 4.0 V V_{NC} floating V_{NC} = 0.3 V or 4.0 V V_{NO} floating V_{COM} = 0.3 V or 4.0 V		4.3	-10		10	-100	100	nA
R_{ON}	On-Resistance (Note 3)	V_{IS} = GND to V_{CC}, I_{IN} = 100 mA	4.3		0.45	0.5		0.55	Ω
			3.6		0.5	0.55		0.65	
			3.0		0.5	0.55		0.65	
			2.7		0.6	0.7		0.8	
			2.3		0.6	0.7		0.8	
			1.8		0.9	1.0		1.1	
R_{FLAT}	On−Resistance Flatness (Note 3) (Note 5)	I_{COM} = 100 mA V_{IS} = 1.5 V	4.3		0.15	0.20		0.20	Ω
			3.6		0.15	0.20		0.20	
			3.0		0.15	0.20		0.20	
			2.7		0.15	0.20		0.20	
			2.3		0.20	0.25		0.25	
			1.8		0.35	0.45		0.45	
ΔR_{ON}	On-Resistance Match Between Channels (Note 3) (Note 4)	I_{COM} = 100 mA V_{IS} = 1.5 V	2.7		0.1				Ω

ELECTRICAL CHARACTERISTICS (AC)

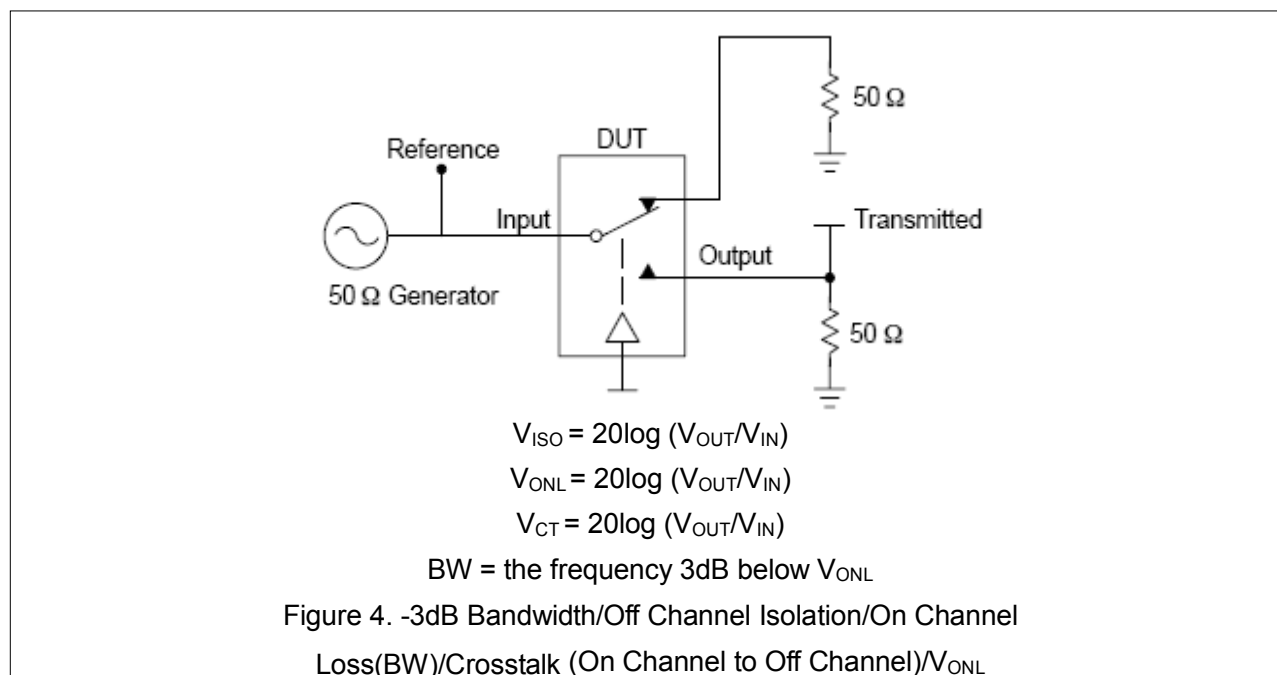| Symbol	Parameter	Test Conditions	$V_{CC} \pm 10\%$	$T_A = 25℃$			Unit
				Min	Typ	Max	
t_{PLH} t_{PHL}	Propagation Delay		1.65 ~ 1.95		0.30		ns
			2.3 ~ 2.7		0.25		
			3.0 ~ 3.3		0.20		
			3.6 ~ 5		0.20		
t_{ON}	Turn−On Time (Figure 1)	$V_{IS} = 0.8$ V	1.65 ~ 1.95		120		ns
		$V_{IS} = 1.5$ V	2.3 ~ 2.7		65	85	
			3.0 ~ 3.3		42	55	
			3.6 ~ 4.3		40	55	
t_{OFF}	Turn−Off Time (Figure 1)	$V_{IS} = 0.8$ V	1.65 ~ 1.95		45		ns
		$V_{IS} = 1.5$ V	2.3 ~ 2.7		18	30	
			3.0 ~ 3.3		16	30	
			3.6 ~ 4.3		15	30	
t_{BBM}	Break-Before-MakeTime (Note6)(Figure 2)	C_L= 35 pF R_{IS} = 50 Ω V_{IS} = 1.5 V	1.65 ~ 1.95	2	17		ns
			2.3 ~ 2.7	2	10		
			3.0 ~ 3.3	2	8		
			3.6 ~ 4.3	2	7		
BW	On-Channel, -3 dB Bandwidth or Frequency Response (Figure 4) R_{IS} = 50 Ω		1.65 ~ 4.3		18		MHz
V_{ISO}	Off-Channel Isolation (Figure 4) F_{IS} = 100 kHz, V_{IN} = GND to $V_{CC,}$ C_L = 5 pF R_L = 50 Ω, V_{IS} = 1V_{RMS}		1.65 ~ 4.3		-66		dB
Q	Charge Injection Select Input to Common I/O (Figure 3)		1.65 ~ 1.95		43		pC
			2.3 ~ 2.7		51		
	V_{IN} = 0 or V_{CC}, R_{IS} = 0 Ω, C_L = 100 pF R_L = 1 mΩ, Q = $C_L \times \Delta V_{OUT}$		3.0 ~ 3.3		51		
			3.6 ~ 4.3		49		
THD	Total Harmonic Distortion THD +Noise F_{IS} = 20 Hz to 20 kHz, R_L = 600 Ω C_L = 50 pF V_{IS} = 2 V_{RMS}		3.0		0.08		%
V_{CT}	Channel - to - Channel Crosstalk (Figure 4) F_{IS} = 100 kHz, V_{IN} = GND to V_{CC} R_L = 50 Ω, C_L = 5 pF, V_{IS} = 1 V_{RMS}		1.65-4.3		-72		dB
C_{IN}	Control Pin Input Capacitance		3.6		3.5		pF
C_{CN}/C_{NO}	NC/NO Port Capacitance		3.6		60		pF
C_{COM}	COM Port Capacitance When Switch is Enabled		3.6		200		pF

Note:

2. Guaranteed by design.

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

4. $\Delta R_{ON} = R_{ON (MAX)} − R_{ON (MIN)}$ between NC1 and NC2 or between NO1 and NO2.

5. Flatness is defined as the difference between the maximum and minimum value of on−resistance as measured over the specified analog signal ranges.
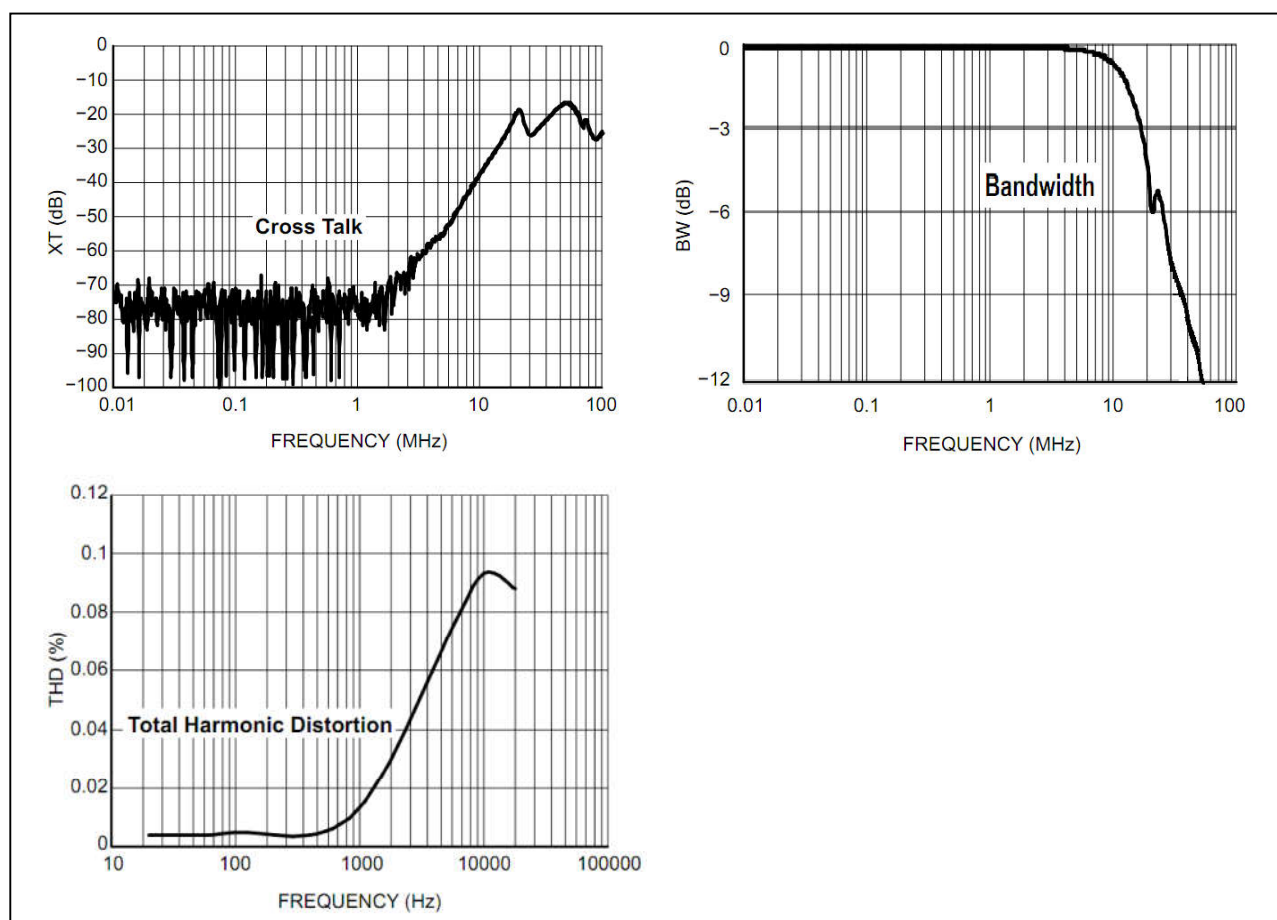
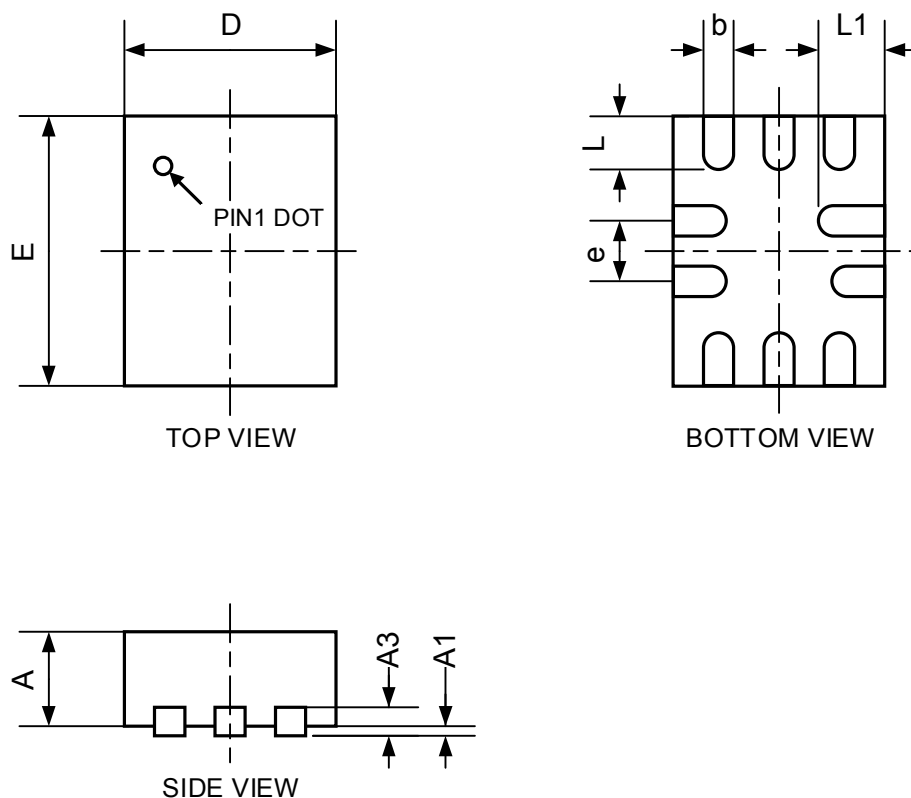6. Guaranteed by design in -40°C.

TEST CIRCUITS

Figure1: t_{ON}/t_{OFF}

Figure2: t_{BBM}

Figure3: Charge Injection
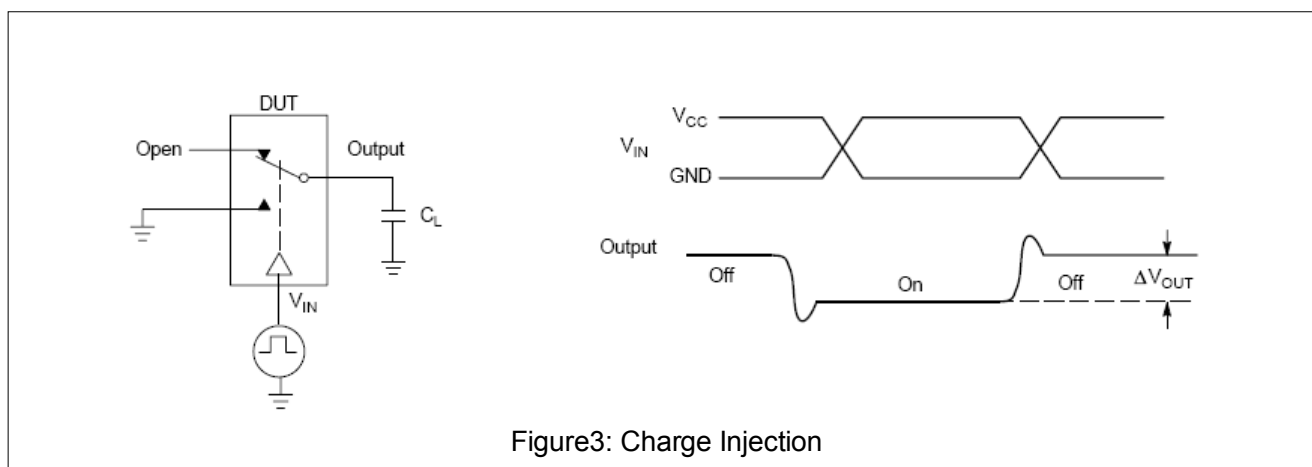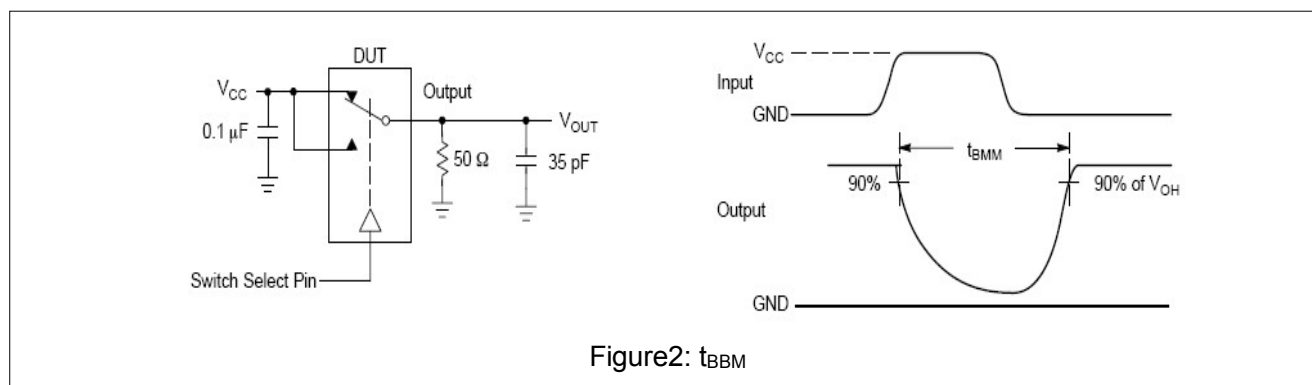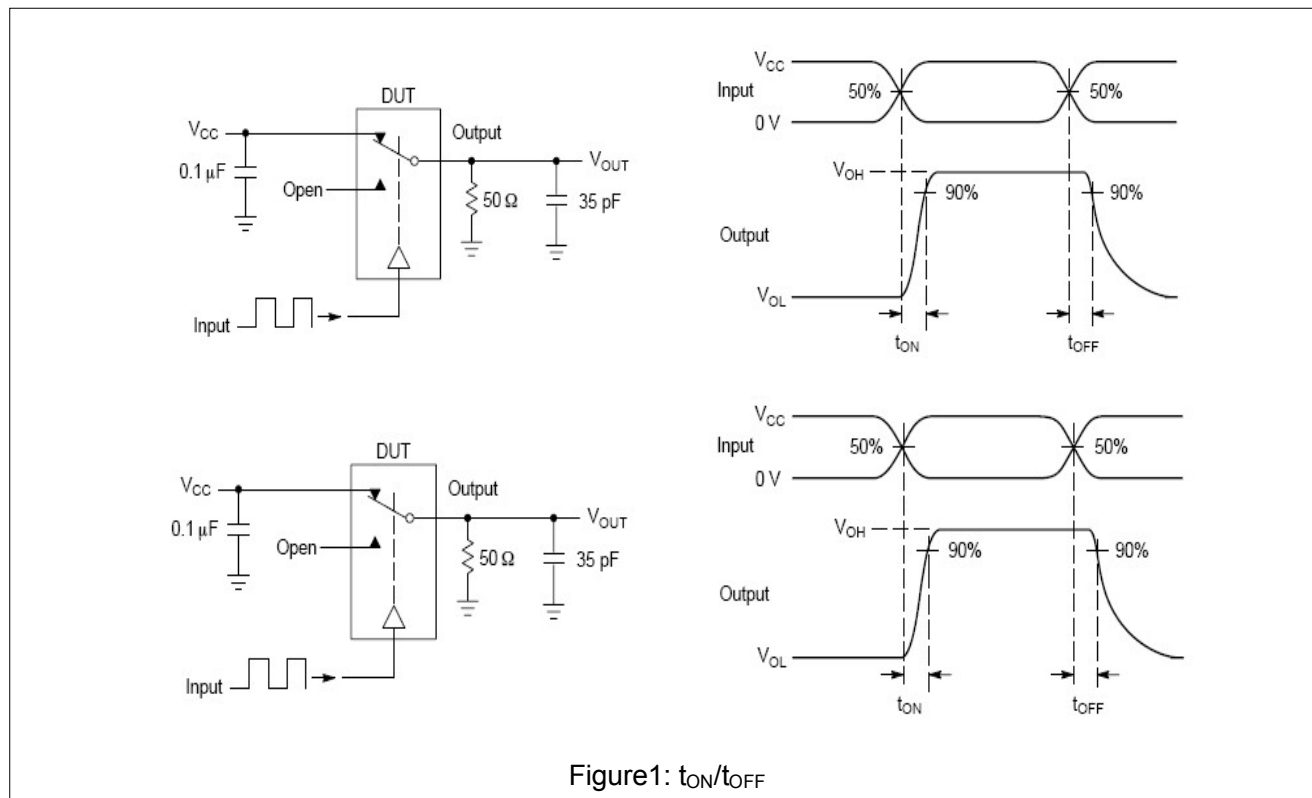
TEST CIRCUITS (Continued)

$V_{ISO} = 20\log (V_{OUT}/V_{IN})$

$V_{ONL} = 20\log (V_{OUT}/V_{IN})$

$V_{CT} = 20\log (V_{OUT}/V_{IN})$

BW = the frequency 3dB below V_{ONL}

Figure 4. -3dB Bandwidth/Off Channel Isolation/On Channel Loss(BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

TYPICAL PERFORMANCE CHARACTERISTICS

PACKAGE OUTLINE

QFN1.8 × 1.4-10

TOP VIEW

BOTTOM VIEW

SIDE VIEW

Symbol	Dimensions In Millimeters		
	Min	Nom	Max
A	0.500	0.550	0.600
A1	0.000		0.050
A3	0.150REF		
D	1.350	1.400	1.450
E	1.750	1.800	1.850
b	0.150	0.200	0.250
L	0.300	0.400	0.500
L1	0.400	0.500	0.600
e	0.400BSC		

PACKAGE OUTLINE

DFN3 × 3-10

TOP VIEW

BOTTOM VIEW

SIDE VIEW
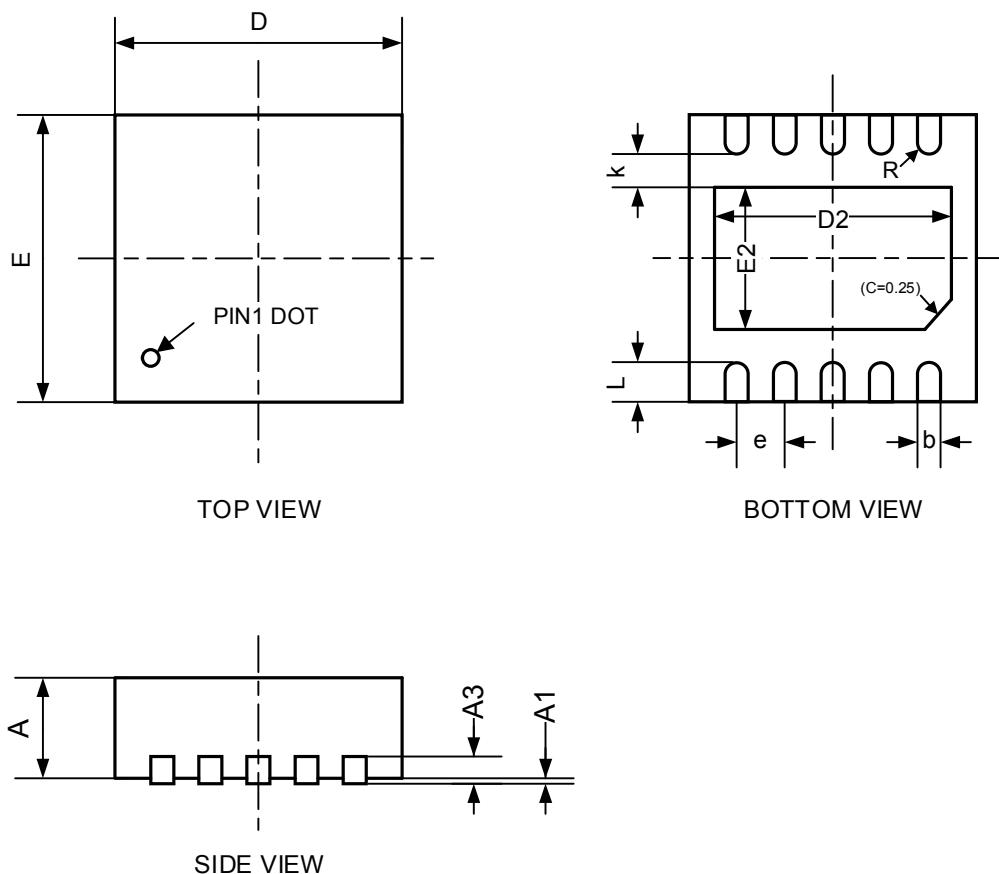
Symbol	Dimensions In Millimeters	
	Min	**Max**
A	0.700	0.800
A1	0.000	0.050
A3	0.203REF	
b	0.180	0.300
D	2.900	3.100
D2	2.450	2.550
e	0.400	0.600
E	2.900	3.100
E2	1.450	1.650
L	0.350	0.450
k	0.150	
R	0.090	

PACKAGE OUTLINE

MSOP-10
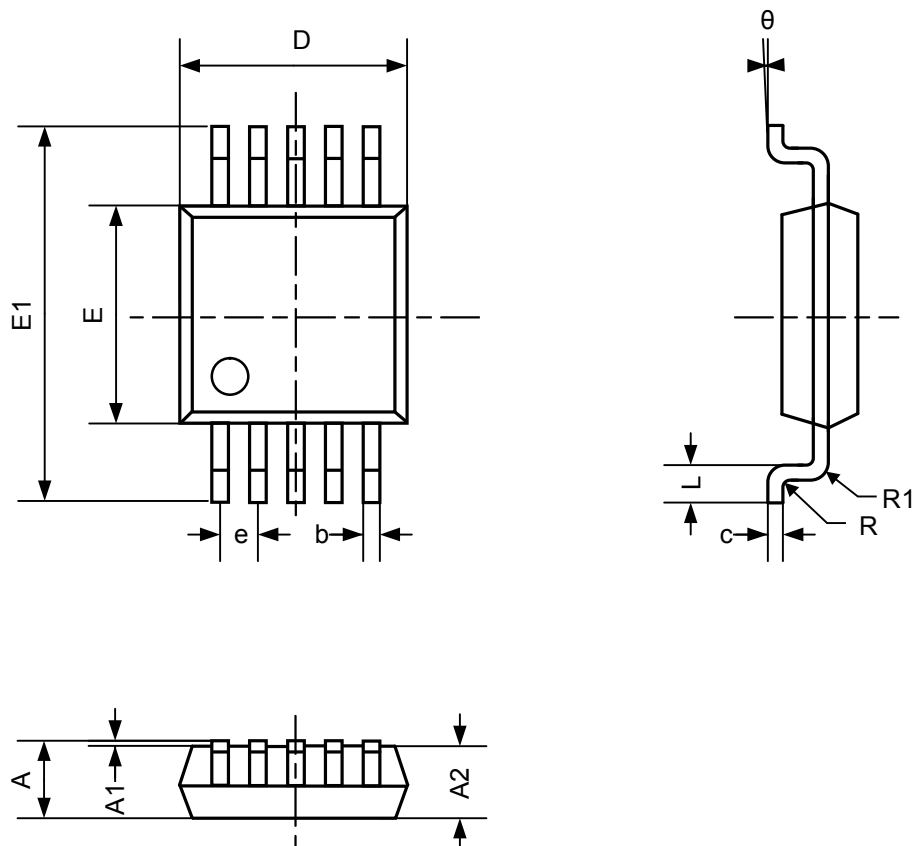
Symbol	Dimensions In Millimeters	
	Min	**Max**
A		1.100
A1	0.000	0.090
A2	0.750	0.950
b	0.180	0.250
c	0.150	0.230
D	2.900	3.100
E	2.900	3.100
E1	4.700	5.100
e	0.500BSC	
L	0.450	0.750
θ	0°	6°
R	0.150REF	
R1	0.150REF	

V 1.3